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FAIRCHILD SEMICONDUCTOR®

March 2014

FSB50550US
Motion SPM® 5 Series

Features

- UL Certified No. E209204 (UL1557)
- 500 V $R_{DS(on)}$ = 1.4 Ω(Max) FRFET MOSFET 3-Phase Inverter with Gate Drivers and Protection
- Separate Open-Source Pins from Low-Side MOSFETs for Three-Phase Current-Sensing
- Active-HIGH Interface, Works with 3.3 / 5 V Logic, Schmitt-trigger Input
- Optimized for Low Electromagnetic Interference
- HVIC for Gate Driving and Under-Voltage Protection
- Isolation Rating: 1500 V_{rms} / min.
- Moisture Sensitive Level (MSL) 3
- RoHS Compliant

Applications

- 3-Phase Inverter Driver for Small Power AC Motor Drives

Related Source

- *AN-9082 - Motion SPM5 Series Thermal Performance by Contact Pressure*

General Description

The FSB50550US is an advanced Motion SPM® 5 module providing a fully-featured, high-performance inverter output stage for AC Induction, BLDC and PMSM motors. These modules integrate optimized gate drive of the built-in MOSFETs (FRFET® technology) to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockouts. The built-in high-speed HVIC requires only a single supply voltage and translates the incoming logic-level gate inputs to the high-voltage, high-current drive signals required to properly drive the module's internal MOSFETs. Separate open-source MOSFET terminals are available for each phase to support the widest variety of control algorithms.



Package Marking & Ordering Information

Device Marking	Device	Package	Reel Size	Packing Type	Quantity
FSB50550US	FSB50550US	SPM5H-023	330mm	Tape-Reel	450

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Absolute Maximum Ratings

Inverter Part (each MOSFET unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V_{DSS}	Drain-Source Voltage of Each MOSFET		500	V
$*I_{D\ 25}$	Each MOSFET Drain Current, Continuous	T_C = 25°C	2.0	A
$*I_{D\ 80}$	Each MOSFET Drain Current, Continuous	T_C = 80°C	1.5	A
$*I_{DP}$	Each MOSFET Drain Current, Peak	T_C = 25°C, PW < 100 μs	5.0	A
$*P_D$	Maximum Power Dissipation	T_C = 25°C, For Each MOSFET	14.5	W

Control Part (each HVIC unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V_{CC}	Control Supply Voltage	Applied Between V_{CC} and COM	20	V
V_{BS}	High-side Bias Voltage	Applied Between V_B and V_S	20	V
V_{IN}	Input Signal Voltage	Applied Between IN and COM	-0.3 ~ V_{CC} + 0.3	V

Thermal Resistance

Symbol	Parameter	Conditions	Rating	Unit
$R_{\theta JC}$	Junction to Case Thermal Resistance	Each MOSFET under Inverter Operating Condition (1st Note 1)	8.6	°C/W

Total System

Symbol	Parameter	Conditions	Rating	Unit
T_J	Operating Junction Temperature		-40 ~ 150	°C
T_{STG}	Storage Temperature		-50 ~ 150	°C
V_{ISO}	Isolation Voltage	60 Hz, Sinusoidal, 1 Minute, Connect Pins to Heat Sink Plate	1500	V_{rms}

1st Notes:

1. For the measurement point of case temperature T_C, please refer to Figure 4.
2. Marking " * " is calculation value or design factor.

Pin descriptions

Pin Number	Pin Name	Pin Description
1	COM	IC Common Supply Ground
2	$V_{B(U)}$	Bias Voltage for U Phase High Side MOSFET Driving
3	$V_{CC(U)}$	Bias Voltage for U Phase IC and Low Side MOSFET Driving
4	$IN_{(UH)}$	Signal Input for U Phase High-Side
5	$IN_{(UL)}$	Signal Input for U Phase Low-Side
6	$V_{S(U)}$	Bias Voltage Ground for U Phase High Side MOSFET Driving
7	$V_{B(V)}$	Bias Voltage for V Phase High Side MOSFET Driving
8	$V_{CC(V)}$	Bias Voltage for V Phase IC and Low Side MOSFET Driving
9	$IN_{(VH)}$	Signal Input for V Phase High-Side
10	$IN_{(VL)}$	Signal Input for V Phase Low-Side
11	$V_{S(V)}$	Bias Voltage Ground for V Phase High Side MOSFET Driving
12	$V_{B(W)}$	Bias Voltage for W Phase High Side MOSFET Driving
13	$V_{CC(W)}$	Bias Voltage for W Phase IC and Low Side MOSFET Driving
14	$IN_{(WH)}$	Signal Input for W Phase High-Side
15	$IN_{(WL)}$	Signal Input for W Phase Low-Side
16	$V_{S(W)}$	Bias Voltage Ground for W Phase High Side MOSFET Driving
17	P	Positive DC–Link Input
18	U	Output for U Phase
19	N_U	Negative DC–Link Input for U Phase
20	N_V	Negative DC–Link Input for V Phase
21	V	Output for V Phase
22	N_W	Negative DC–Link Input for W Phase
23	W	Output for W Phase

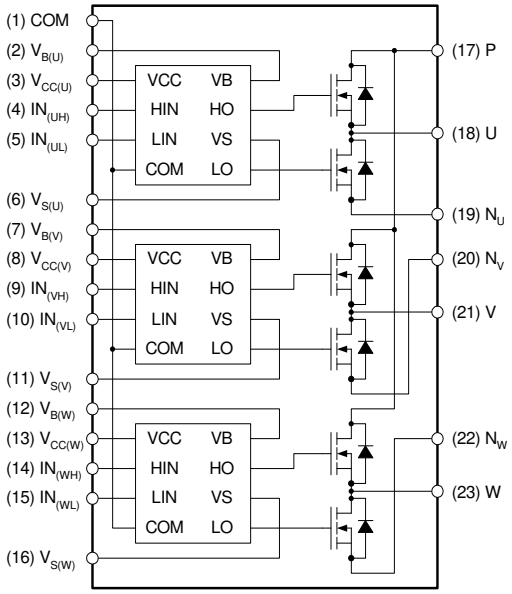


Figure 1. Pin Configuration and Internal Block Diagram (Bottom View)

1st Notes:

3. Source terminal of each low-side MOSFET is not connected to supply ground or bias voltage ground inside Motion SPM® 5 product. External connections should be made as indicated in Figure 3.

Electrical Characteristics (T_J = 25°C, V_{CC} = V_{BS} = 15 V unless otherwise specified.)

Inverter Part (each MOSFET unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
BV_{DSS}	Drain - Source Breakdown Voltage	V_{IN} = 0 V, I_D = 250μA (2nd Note 1)	500	-	-	V
$\Delta BV_{DSS}/\Delta T_J$	Breakdown Voltage Temperature Coefficient	I_D = 250μA, Referenced to 25°C	-	0.53	-	V
I_{DSS}	Zero Gate Voltage Drain Current	V_{IN} = 0 V, V_{DS} = 500 V	-	-	250	μA
$R_{DS(on)}$	Static Drain - Source Turn-On Resistance	V_{CC} = V_{BS} = 15 V, V_{IN} = 5 V, I_D = 1.2 A	-	1.0	1.4	Ω
V_{SD}	Drain - Source Diode Forward Voltage	V_{CC} = V_{BS} = 15V, V_{IN} = 0 V, I_D = -1.2 A	-	-	1.2	V
t_{ON}	Switching Times	V_{PN} = 300 V, V_{CC} = V_{BS} = 15 V, I_D = 1.2 A V_{IN} = 0 V ↔ 5 V, Inductive Load L = 3 mH High- and Low-Side MOSFET Switching (2nd Note 2)	-	600	-	ns
t_{OFF}			-	500	-	ns
t_{rr}			-	100	-	ns
E_{ON}			-	60	-	μJ
E_{OFF}			-	10	-	μJ
RBSOA	Reverse Bias Safe Operating Area	V_{PN} = 400 V, V_{CC} = V_{BS} = 15 V, I_D = I_{DP}, V_{DS} = BV_{DSS}, T_J = 150°C High- and Low-Side MOSFET Switching (2nd Note 3)	Full Square			

Control Part (each HVIC unless otherwise specified.)

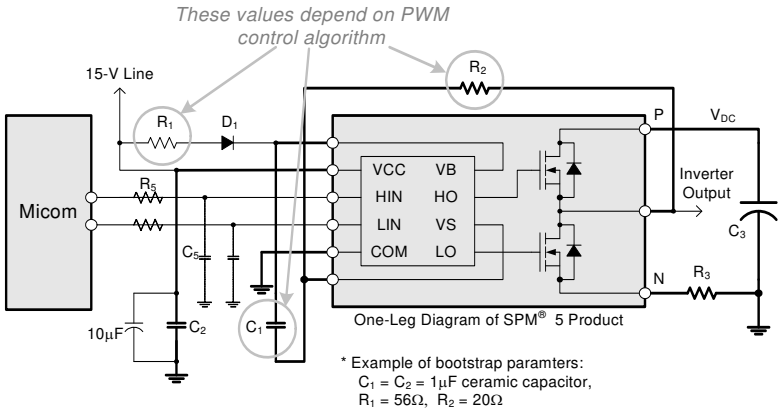
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
I_{QCC}	Quiescent V_{CC} Current	V_{CC} = 15 V, V_{IN} = 0 V	Applied Between V_{CC} and COM	-	-	160	μA
I_{QBS}	Quiescent V_{BS} Current	V_{BS} = 15 V, V_{IN} = 0 V	Applied Between $V_{B(U)}$ - U, $V_{B(V)}$ - V, $V_{B(W)}$ - W	-	-	100	μA
UV_{CCD}	Low-Side Under-Voltage Protection (Figure 8)	V_{CC} Under-Voltage Protection Detection Level		7.4	8.0	9.4	V
UV_{CCR}		V_{CC} Under-Voltage Protection Reset Level		8.0	8.9	9.8	V
UV_{BSD}	High-Side Under-Voltage Protection (Figure 9)	V_{BS} Under-Voltage Protection Detection Level		7.4	8.0	9.4	V
UV_{BSR}		V_{BS} Under-Voltage Protection Reset Level		8.0	8.9	9.8	V
V_{IH}	ON Threshold Voltage	Logic HIGH Level	Applied between IN and COM	3.0	-	-	V
V_{IL}	OFF Threshold Voltage	Logic LOW Level		-	-	0.8	V
I_{IH}	Input Bias Current	V_{IN} = 5V	Applied between IN and COM	-	10	20	μA
I_{IL}		V_{IN} = 0V		-	-	2	μA

2nd Notes:

1. BV_{DSS} is the absolute maximum voltage rating between drain and source terminal of each MOSFET inside Motion SPM® 5 product. V_{PN} should be sufficiently less than this value considering the effect of the stray inductance so that V_{PN} should not exceed BV_{DSS} in any case.
2. t_{ON} and t_{OFF} include the propagation delay of the internal drive IC. Listed values are measured at the laboratory test condition, and they can be different according to the field applications due to the effect of different printed circuit boards and wirings. Please see Figure 4 for the switching time definition with the switching test circuit of Figure 5.
3. The peak current and voltage of each MOSFET during the switching operation should be included in the Safe Operating Area (SOA). Please see Figure 5 for the RBSOA test circuit that is same as the switching test circuit.

Recommended Operating Condition

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{PN}	Supply Voltage	Applied Between P and N	-	300	400	V
V_{CC}	Control Supply Voltage	Applied Between V_{CC} and COM	13.5	15.0	16.5	V
V_{BS}	High-Side Bias Voltage	Applied Between V_B and V_S	13.5	15.0	16.5	V
$V_{IN(ON)}$	Input ON Threshold Voltage	Applied Between IN and COM	3.0	-	V_{CC}	V
$V_{IN(OFF)}$	Input OFF Threshold Voltage		0	-	0.6	V
t_{dead}	Blanking Time for Preventing Arm-Short	$V_{CC} = V_{BS} = 13.5 \sim 16.5$ V, $T_J \leq 150°C$	1.0	-	-	μs
f_{PWM}	PWM Switching Frequency	$T_J \leq 150°C$	-	15	-	kHz



HIN	LIN	Output	Note
0	0	Z	Both FRFET Off
0	1	0	Low side FRFET On
1	0	V_{DC}	High side FRFET On
1	1	Forbidden	Shoot through
Open	Open	Z	Same as (0,0)

Figure 2. Recommended MCU Interface and Bootstrap Circuit with Parameters

3rd Notes:

1. It is recommended the bootstrap diode D_1 to have soft and fast recovery characteristics with 600 V rating.
2. Parameters for bootstrap circuit elements are dependent on PWM algorithm. For 15 kHz of switching frequency, typical example of parameters is shown above.
3. RC-coupling (R_5 and C_5) and C_4 at each input of Motion SPM 5 product and MCU (Indicated as Dotted Lines) may be used to prevent improper signal due to surge-noise.
4. Bold lines should be short and thick in PCB pattern to have small stray inductance of circuit, which results in the reduction of surge-voltage. Bypass capacitors such as C_1, C_2 and C_3 should have good high-frequency characteristics to absorb high-frequency ripple-current.

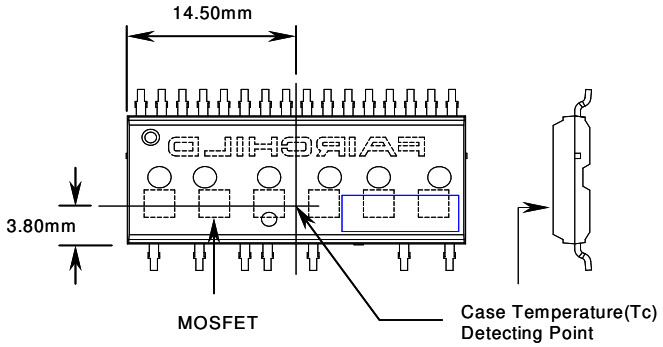
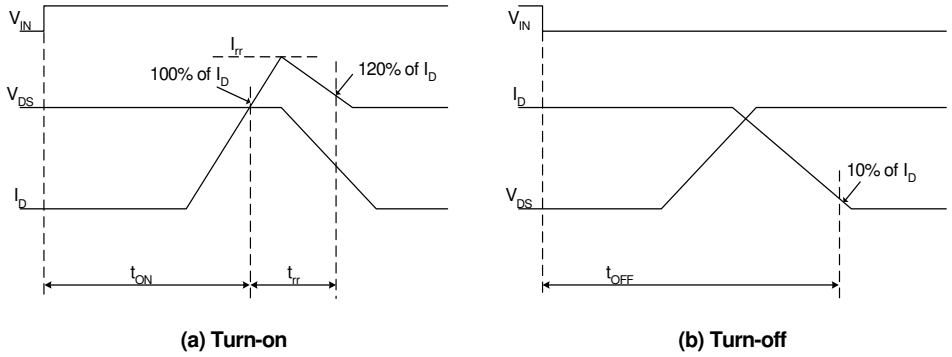


Figure 3. Case Temperature Measurement

3rd Notes:

5. Attach the thermocouple on top of the heat-sink of SPM 5 package (between SPM 5 package and heatsink if applied) to get the correct temperature measurement.



(a) Turn-on **(b) Turn-off**

Figure 4. Switching Time Definitions

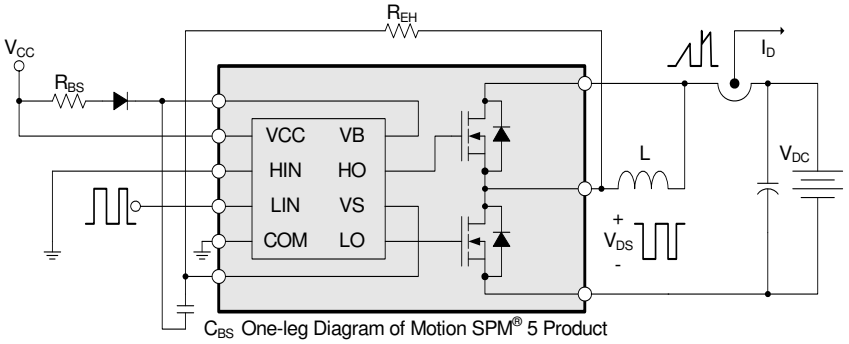


Figure 5. Switching and RBSOA (Single-pulse) Test Circuit (Low-side)

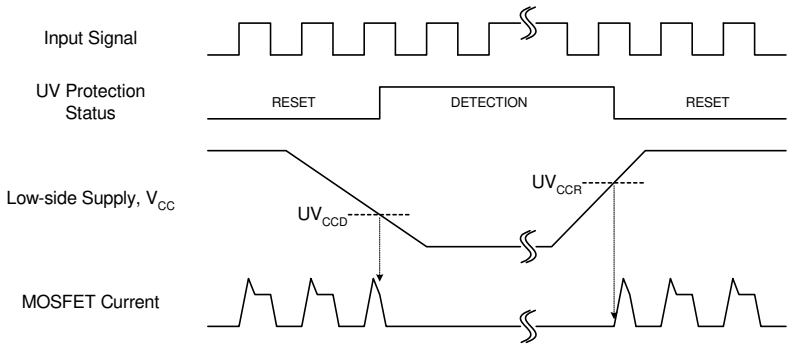


Figure 6. Under-Voltage Protection (Low-Side)

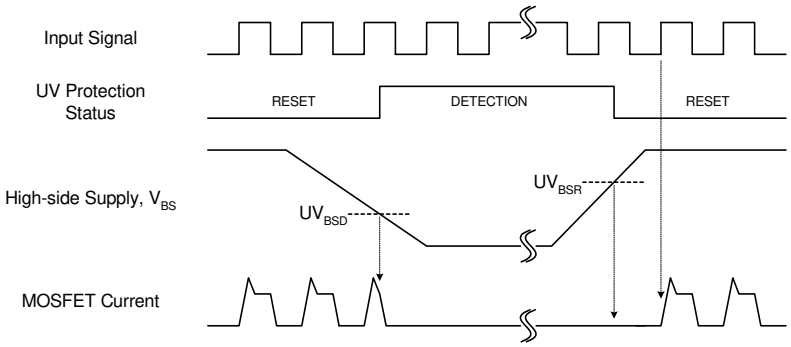


Figure 7. Under-Voltage Protection (High-Side)

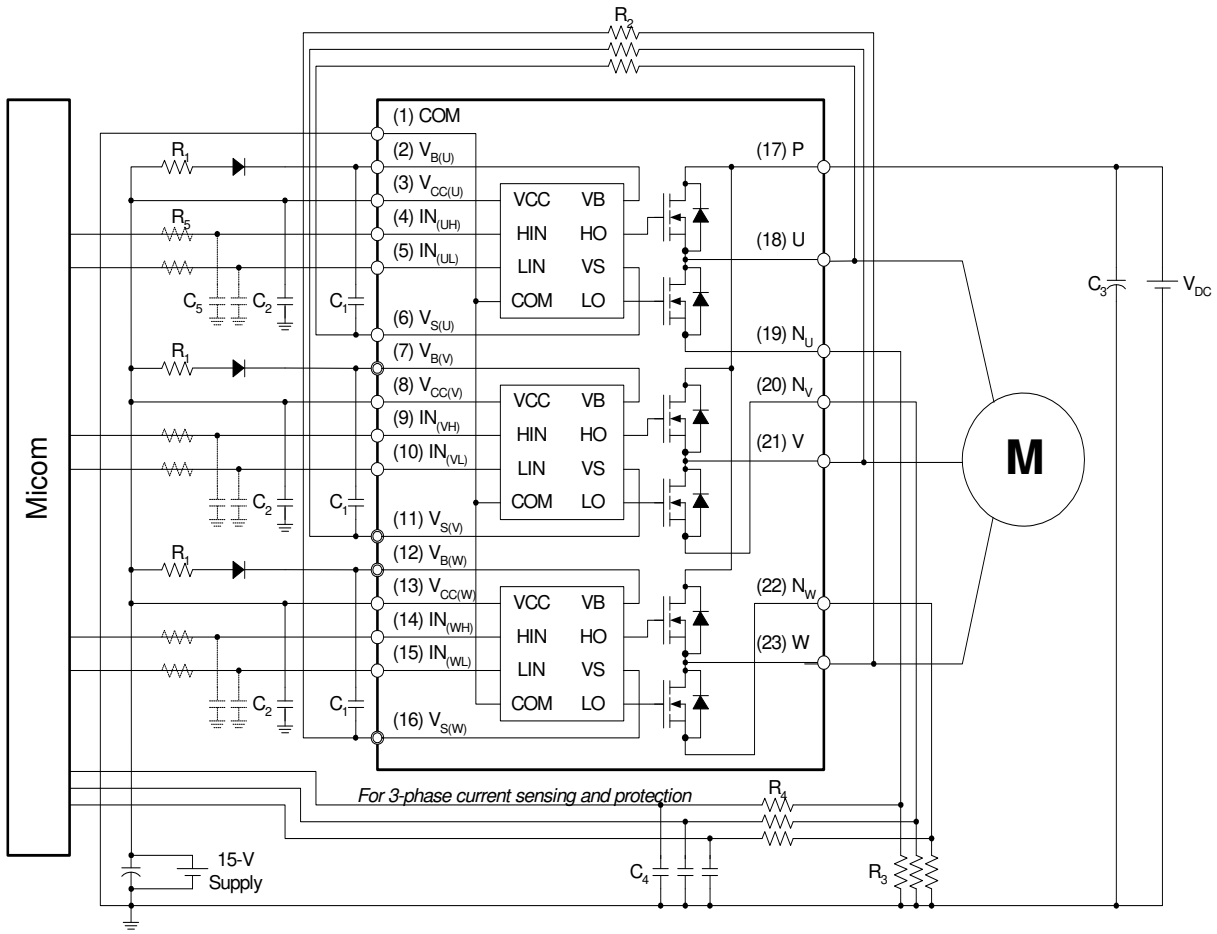
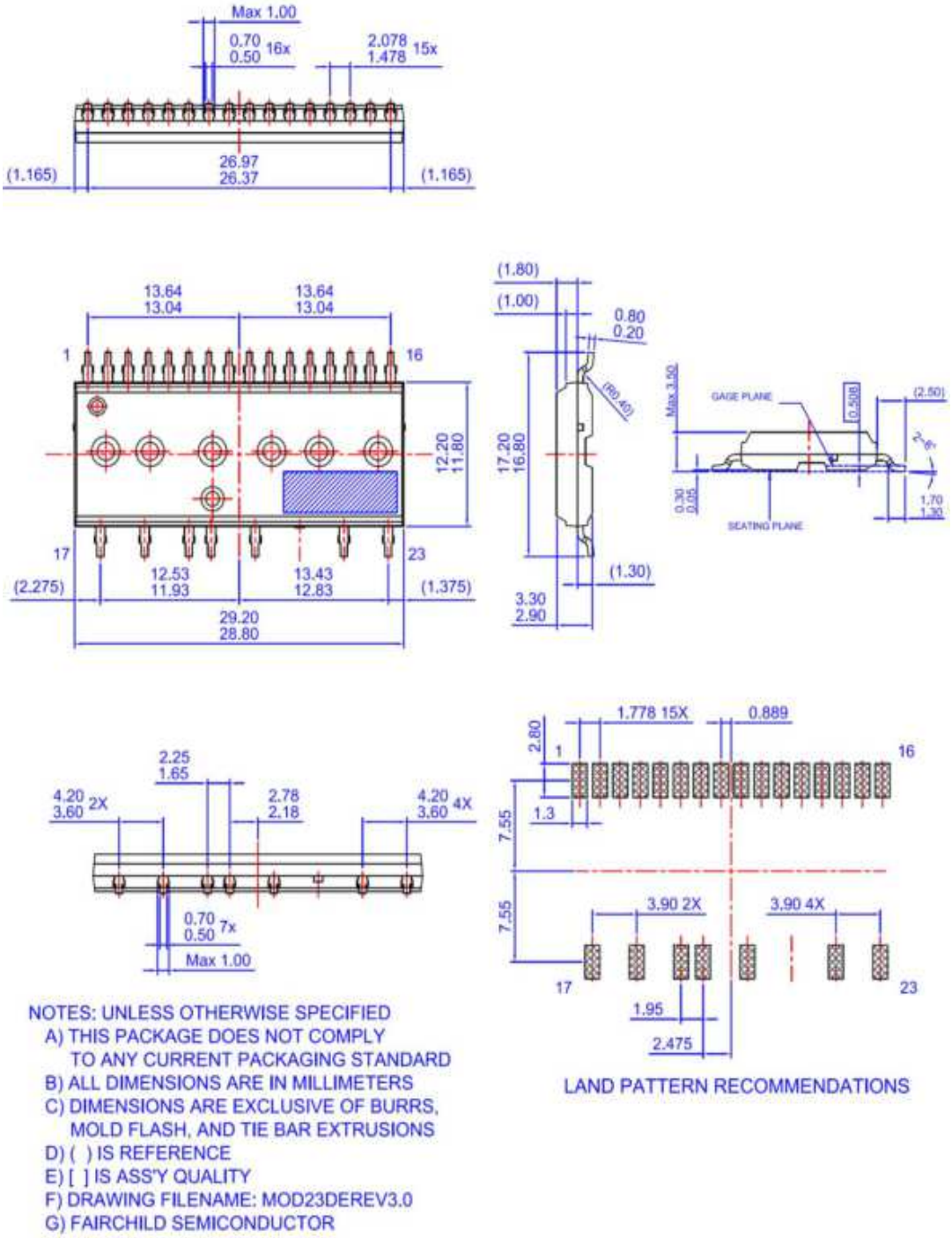


Figure 8. Example of Application Circuit

4th Notes:

1. About pin position, refer to Figure 1.
2. RC-coupling (R_5 and C_5, R_4 and C_6) and C_4 at each input of Motion SPM® 5 product and MCU are useful to prevent improper input signal caused by surge-noise.
3. The voltage-drop across R_3 affects the low-side switching performance and the bootstrap characteristics since it is placed between COM and the source terminal of the low-side MOSFET. For this reason, the voltage-drop across R_3 should be less than 1 V in the steady-state.
4. Ground-wires and output terminals, should be thick and short in order to avoid surge-voltage and malfunction of HVIC.
5. All the filter capacitors should be connected close to Motion SPM 5 product, and they should have good characteristics for rejecting high-frequency ripple current.

Detailed Package Outline Drawings



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